

Abstracts

Time domain global modeling of EM propagation in semiconductor using irregular grids

Hsiao-Ping Tsai, R. Coccioli and T. Itoh. "Time domain global modeling of EM propagation in semiconductor using irregular grids." 2000 MTT-S International Microwave Symposium Digest 00.1 (2000 Vol. 1 [MWSYM]): 367-370.

A time domain technique for the combined solution of Maxwell's equations and transport equations on an irregular grid has been developed. The code implemented has been tested against analytical models and applied to characterize EM propagation at microwave frequencies in semiconductor slab with arbitrary doping profile.

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